

Ratiometric Linear Hall-Effect IC, Analog Output



1 Product Description

The MT910X device is a linear Hall effect IC that responds proportionally to magnetic flux density. The device can be used for accurate position sensing in a wide range of applications.

The device operates from 3.0V to 5.5V power supplies. When no magnetic field is present, the analog output drives ½ of Vcc. The output changes linearly with the applied magnetic flux density, and four sensitivity options enable maximal output voltage swing based on the required sensing range. North and south magnetic poles produce unique voltages.

The MT910X family provides a variety of packages to customers. SOT-23 (Thin Outline) for surface mount and flat TO-92 for through-hole mount. All packages are RoHS compliant.

2 Features

- BCD Technology
- Factory-programmed
- Ratiometric Rail to Rail Analog Output
- Low-Noise Output
- 3.0~5.5V Operating Vcc Range
- -40°C~150°C Operating Temperature
- Package Option: Flat TO-92

SOT-23 (Thin Outline)

Magnetic Sensitivity Option:

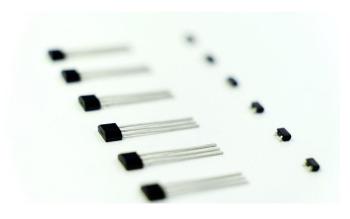
1.50mV/Gs MT9101 Series @Vcc = 5V 2.50mV/Gs MT9102 Series @Vcc = 5V 3.40mV/Gs MT9103 Series @Vcc = 5V 5.00mV/Gs MT9105 Series @Vcc = 5V 1.00mV/Gs MT9101 Series @Vcc = 3.3V 1.60mV/Gs MT9102 Series @Vcc = 3.3V 2.15mV/Gs MT9103 Series @Vcc = 3.3V

3.15mV/Gs MT9105 Series @Vcc = 3.3V

RoHS Compliant: (EU)2015/863

3 Product Overview of MT910X

Part No.	Description
MT910XA	Flat TO-92, bulk packaging (1000pcs/bag)
MT910XET	SOT-23 (Thin Outline), tape & reel (3000pcs/bag)



4 Applications

- Home appliances
- Industrial
- Speed Detection
- Position Detection
- Magnetic Encoder
- Ferrous Metal Sensing
- Vibration Sensing
- Weight Sensing

5. Pin Configuration and Functions

	Vcc	Out	GND
SOT-23 (Thin Outline)	1	2	3
Flat TO-92	1	3	2
Description	Power	Output	Ground

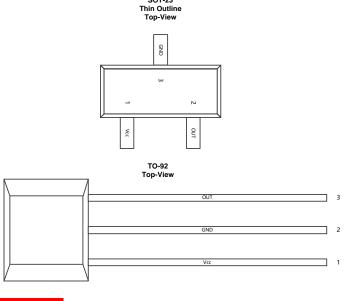




Table of Contents

1	Product Description	1
2	Features	1
3	Product Overview of MT910X	1
4	Applications	1
5	Pin Configuration and Functions	1
6	Transfer Characteristics	3
7	Function Description.	3
8	Feature Description.	3
9	Functional Block Diagram	4
10	Electrical and Magnetic Characteristics	4
	10.1 Absolute Maximum Ratings	4
	10.2 ESD Ratings	4
	10.3 Electrical Specifications	5
	10.4 Magnetic Characteristics	5
	10.5 Characteristic Performance	6
11	Typical Application Circuit	8
12	Package Material Information	9
	12.1 SOT-23 (Thin Outline) Package Information	9
	12.2 Flat TO-92 Package Information	10
13	Copy Rights and Disclaimer	11

Reversion History

1 Orio	ginally	Version
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2 Version 1.1

3 Version 1.2

4 Version 1.3

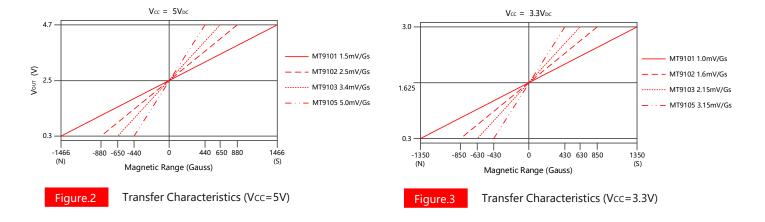
5 Version 1.4

Update characteristic performance & Noise Update parameters @ 3.3V Vcc Update the marking spec of SOT-23 (Thin Outline) Update the drawing information of flat TO-92



6 Transfer Characteristics

Finure.2 shows four sensitivity options enable maximal output voltage swing based on the required sensing range



7 Function Description

The device produces a linear response when the output voltage is within the specified voltage range. Outside this range, sensitivity is reduced and nonlinear

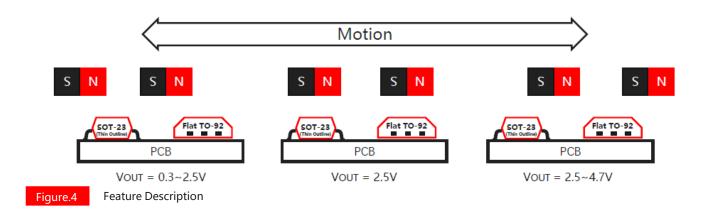
8 Feature Description

The MT910X device is sensitive to the magnetic field component that is perpendicular to the top of the package

When the magnetic field moving from the left side of the IC to the middle which showed in the left of the Figure.3, the Vout changing from 0.3 to 2.5V linearity when Vcc=5V

When the magnetic field located at the middle of the IC which showed in the middle of the Figure.3, the VOUT is 2.5V (1/2 of the VCC=5V)

When the magnetic field moving from the middle side of the IC to the right which showed in the right of the Figure.3, the Vout changing from 2.5 to 4.7V linearity when Vcc=5V





9 Functional Block Diagram

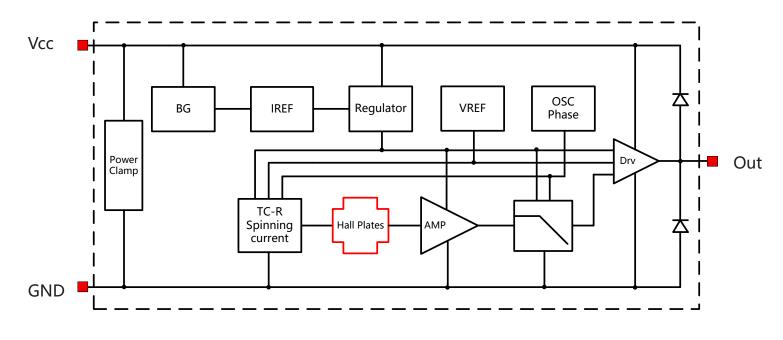


Figure.5 Functional Block Diagram

10 Electrical and Magnetic Characteristics

10.1 Absolute Maximum Ratings

Absolute maximum ratings are limited values to be applied individually, and beyond which the serviceability of the circuit may be impaired. Functional operability is not necessarily implied. Exposure to absolute maximum rating conditions for an extended period of time may affect device reliability.

Symbol	Parameters	Min	Max	Units
Vcc	Supply Voltage	-	30	V
VRCC	Reverse Battery Voltage	-0.2	-	V
Vout	Output Voltage	-	30	V
Іоит	Continuous Output Current	-5	5	mA
TA	Operating Ambient Temperature	-40	150	$^{\circ}$
Ts	Storage Temperature	-40	160	$^{\circ}$
TJ	Junction Temperature	-	165	$^{\circ}$

10.2 ESD Ratings

Symbo	ol .	Reference	Values	Unit
Vrcn	Human-body model (HBM)	AEC-Q100-002	±3000	V
VESD	Charged-device model (CDM)	AEC-Q100-011	±1000	V



10.3 Electrical Specifications

At $T_A=-40\sim150$ °C, $V_{CC}=3.0V\sim5.5V$ (unless otherwise specified)

Symbol	Parameters	Test Condition	Min	Тур	Max	Unit
Vcc	Supply Voltage		3.0	-	5.5	V
lcc	Supply Current	Vcc=5V; B=0	-	6.7	8.6	mA
icc	зирріу сипепі	Vcc=3.3V; B=0	-	6.0	7.0	mA
Тро	Power on Time	dVcc/dt≥5V/us	-	-	30	us
Isink	Sink Current	B=0; Vout=Vcc	-1.5	-	-	mA
Isource	Source Current	B=0; Vout=0	-	-	1.5	mA
Bw	Bandwidth		20	30	-	KHz
Fc	Chopper Frequency		-	780	-	KHz
	Noise	B=0; T _A =25°C	-	1.9	2.6	mG/root(Hz)
		MT9101; T _A =25°C	-	1.46	-	mVRMS
NF		MT9102; T _A =25°C	-	2.44	-	m V RMS
		MT9103; T _A =25°C	-	3.32	-	mVRMS
		MT9105; T _A =25°C	-	4.88	-	m V RMS
Rouт	Output Resistance	IOUT<=±1.5mA VOUT=2.5V	-	2	4	Ohm
RL	Output Loading Resistance	IOUT<=1.5mA Output to GND or to Vcc	4.7	-	-	Kohm
CL	Output Loading Capacitance	lout<=±1.5mA Output to GND	-	-	10	nF
DTII	Thermal Resistance of SOT	-23 (Thin outline)	-	301	-	°C/W
Rтн	Thermal Resistance of Fla	t TO-92	-	230	-	°C/W

10.4 Magnetic Characteristics

At T_A=-40~150 °C, Vcc=3.0V~5.5V (unless otherwise specified)

Symbol	Parameters	Test Condition	Min	Тур	Max	Unit
Lin	Linearity		-1.5	-	1.5	%
VNULL	Quiescent Voltage	Vcc=5V; B=0 Ta=25°C	2.475	2.500	2.525	V
		Vcc=3.3V; B=0 T _A =25°C	1.630	1.650	1.670	V
VNULL (V)	Ratiometry, VNULL	Vcc=4.5V~5.5V	-1.5	-	1.5	%
VNULL (T)	VNULL Variation Over Temperature	Vcc=4.5V~5.5V	-1.5	-	1.5	%
Sens (T)	Sens Variation Over Temperature		-10	-	10	%

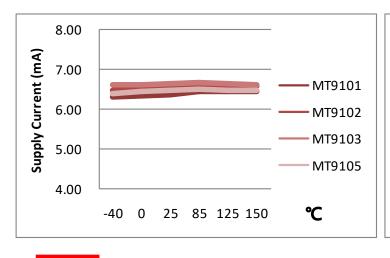


10.4 Magnetic Characteristics (continued)

At T_A=-40~150 °C, Vcc=3.0V~5.5V (unless otherwise specified)

Symbol	Parameters	Test Condition	Min	Тур	Max	Unit
	Sensitivity	MT9101	1.395	1.500	1.605	mV/Gs
		MT9102	2.325	2.500	2.675	mV/Gs
	T _A =25°C; Vcc=5V	MT9103	3.162	3.400	3.638	mV/Gs
Sens		MT9105	4.650	5.000	5.350	mV/Gs
S EINS		MT9101	0.900	1.000	1.100	mV/Gs
	Sensitivity	MT9102	1.488	1.600	1.712	mV/Gs
	T _A =25°C; Vcc=3.3V	MT9103	2.000	2.150	2.300	mV/Gs
		MT9105	2.930	3.150	3.370	mV/Gs
		MT9101	-	±1466	-	Gs
	Magnetic Field Range	MT9102	-	±880	-	Gs
	T _A =25°C; Vcc=5V	MT9103	-	±650	-	Gs
В		MT9105	-	±440	-	Gs
В		MT9101	-	±1350	-	Gs
	Magnetic Field Range T _A =25°C; Vcc=3.3V	MT9102	-	±850	-	Gs
		MT9103	-	±630	-	Gs
		MT9105	-	±430	-	Gs

10.5 Characteristic Performance



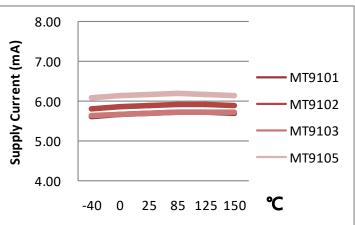


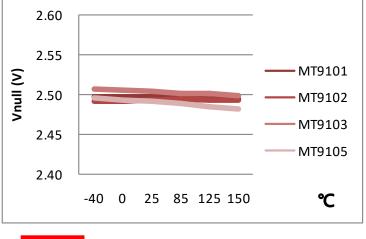
Figure.6 Supply

Supply Current vs. Temperature (At Vcc=5.0V)

Figure.7 Supply Current vs. Temperature (At Vcc=3.3V)



10.5 Characteristic Performance (continued)



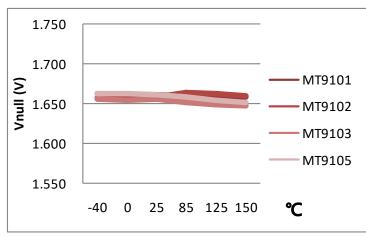
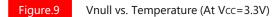
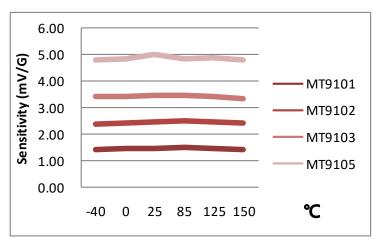


Figure.8 Vnull vs. Temperature (At Vcc=5.0V)





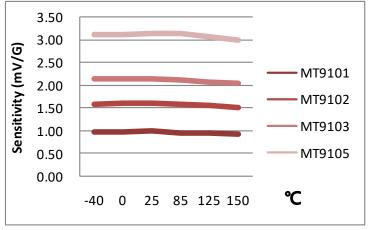


Figure.10 Sensitivity vs. Temperature (At Vcc=5.0V)

Figure.11 Sensitivity vs. Temperature (At Vcc=3.3V)

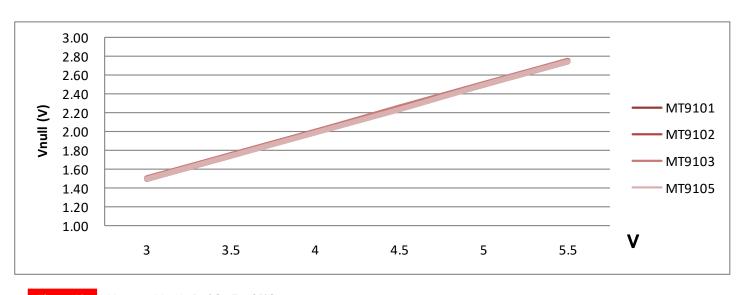


Figure.12 VNULL vs. Vcc (At B=0Gs; Ta=25°C)



10.5 Characteristic Performance (continued)

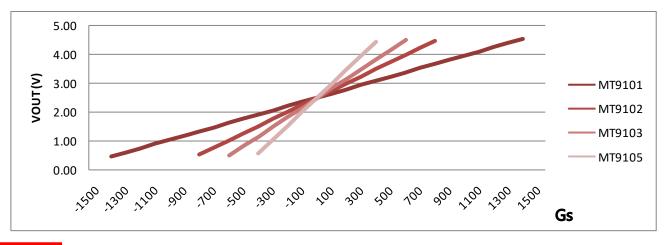


Figure.13 Vouτ vs. Magnetic Field (At Vcc=5.0V; Ta=25°C)

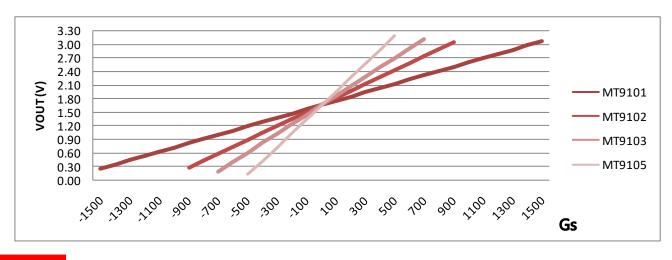
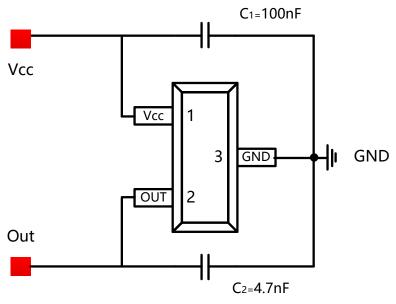


Figure.14 Vouτ vs. Magnetic Field (At Vcc=3.3V; Ta=25°C)

11 Typical Application Circuit

MT9101ET as example



8

Figure.15 Typical Application Circuit



12 Package Material Information (For Reference Only – Not for Tooling Use)

12.1 SOT-23 (Thin Outline) Package Information

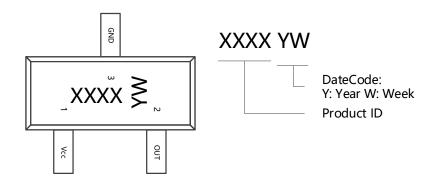


Figure.16 SOT-23 (Thin Outline) Chip Marking Spec

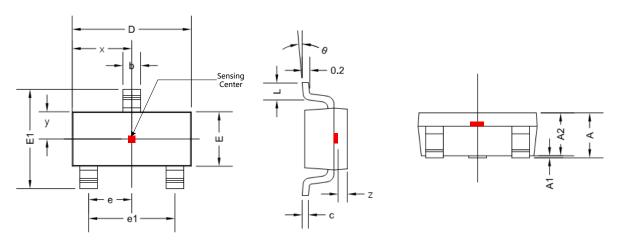


Figure.17 SOT-23 (Thin Outline) Package Drawing

			- •	
Symbol	Dimensions in Millimeters		Dimension	s in Inches
	Min	Max	Min	Max
Α	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
С	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
е	0.95	0 TYP	0.037	TYP
e1	1.800	2.000	0.071	0.079
L	0.55	0 REF	0.022	REF
L1	0.300	0.500	0.012	0.020
θ	0 °	8 °	0 °	8 °
х	1.46	0 TYP	0.057	TYP
у	0.65	0 TYP	0.026	TYP
Z	0.50	0 TYP	0.020	TYP



12.2 Flat TO-92 Package Information

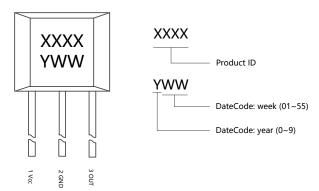


Figure.18 Flat TO-92 Chip Marking Spec

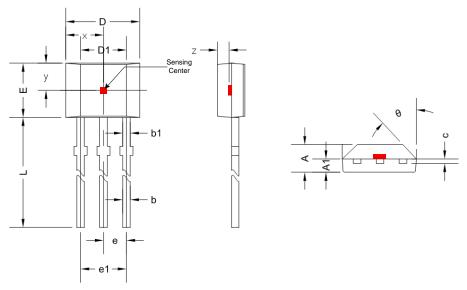


Figure.19 Flat TO-92 Package Drawing

Symbol	Dimensions i	n Millimeters	Dimension	s in Inches
	Min	Max	Min	Max
Α	1.420	1.620	0.056	0.064
A1	0.660	0.860	0.026	0.034
b	0.330	0.430	0.013	0.017
b1	0.330	0.430	0.013	0.017
С	0.330	0.510	0.013	0.020
D	3.900	4.100	0.154	0.161
D1	2.280	2.680	0.090	0.106
E	3.050	3.250	0.120	0.128
e	1.270	O TYP	0.050) TYP
e1	2.440	2.640	0.096	0.104
L	14.350	14.750	0.564	0.580
θ	45 °	`TYP	45 °	TYP
Х	2.025	5 TYP	0.080) TYP
У	1.54	5 TYP	0.061	TYP
Z	0.500	O TYP	0.020) TYP



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